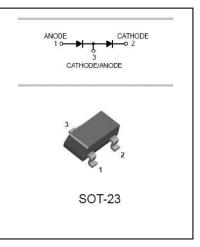


Dual series switching diode

FEATURES

- Fast switching speed Max:6ns
- High conductance
- Connected in series
- Surface mount package ideally suited for automatic insertion



APPLICATIONS

• Small signal switching

MAXIMUM RATING @ Ta=25°C unless otherwise specified

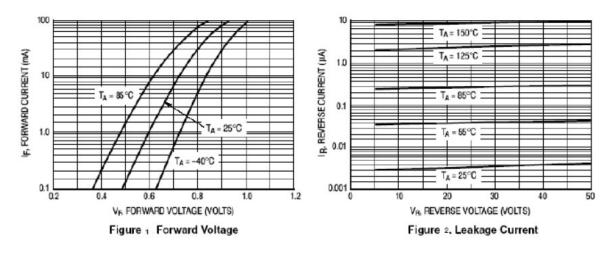
Parameter	Symbol	Value	Unit
Non repetitive peak reverse voltage	V _{RM}	80	V
Repetitive peak reverse voltage Working peak reverse voltage DC Reverse voltage	V _{RRM} V _{RWM} V _R	70	V
Peak forward surge current @t=1.0s @t=1.0µs	I _{FSM}	1 4.5	mA
Forward current	I _F	250	mA
Power dissipation	P _d	300	mW

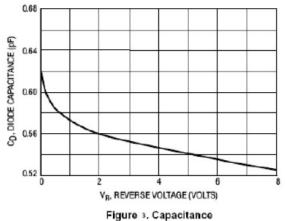


MMBD1203

ELECTRICAL CHARACTERISTICS @ Ta=25 $^\circ C$ unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	V _(BR)	Ι _R = 100μΑ	70		V
Reverse voltage leakage current	I _R	V _R =70V		2.5	μA
Forward voltage	V _F	I _F =1mA I _F =10mA I _F =50mA I _F =150mA		715 855 1000 1250	mV
Diode capacitance	CD	V _R =0V f=1MHz		1.5	pF
Reverse recovery time	t _{rr然}	I _F =I _R =10mA V _R =5V R _C =100Ω		6	nS





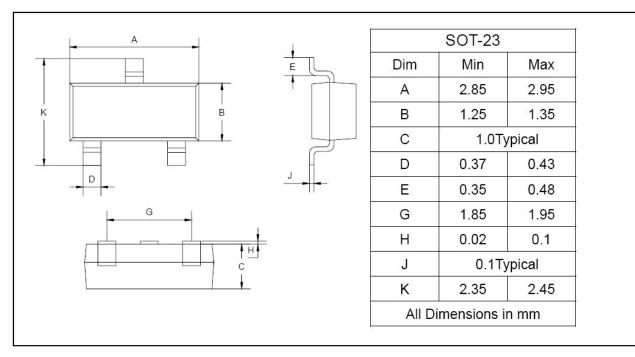


MMBD1203

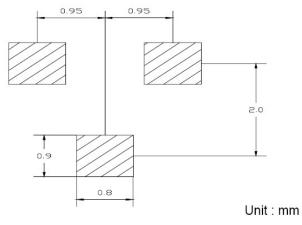
SOT-23

PACKAGE OUTLINE

Plastic surface mounted package



SOLDERING FOOTPRINT



单击下面可查看定价,库存,交付和生命周期等信息

>>SHIKUES(时科)